

# XBS104V14R-G

ETR1610-002

Schottky Barrier Diode, 1A, 40V Type

## FEATURES

Forward Voltage	: $V_F=0.365V$ (TYP.)
Forward Current	: $I_{F(AV)}=1A$
Repetitive Peak Reverse Voltage	: $V_{RM}=40V$
Environmentally Friendly	: EU RoHS Compliant, Pb Free

## ABSOLUTE MAXIMUM RATINGS

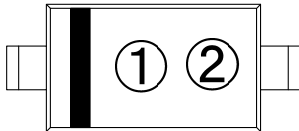
Ta=25°C

PARAMETER	SYMBOL	RATINGS	UNIT
Repetitive Peak Reverse Voltage	$V_{RM}$	40	V
Reverse Voltage (DC)	$V_R$	40	V
Forward Current (Average)	$I_{F(AV)}$	1	A
Non Continuous Forward Surge Current <sup>*1</sup>	$I_{FSM}$	20	A
Junction Temperature	$T_j$	125	°C
Storage Temperature Range	$T_{stg}$	-55~+150	°C

\*1 : Non continuous high amplitude 60Hz half-sine wave.

\* When the IC is operated continuously under high load conditions such as high temperature, high current and high voltage, it may have the case that reliability reduces drastically even if under the absolute maximum ratings. Adequate "Derating" should be taken into consideration while designing.

## MARKING RULE



- ①: 0 (Product Number)  
②: Assembly Lot Number

## PRODUCT NAME

PRODUCT NAME	DEVICE ORIENTATION
XBS104V14R-G	SOD-123A(Halogen & Antimony free)
XBS104V14R	SOD-123A

\* The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

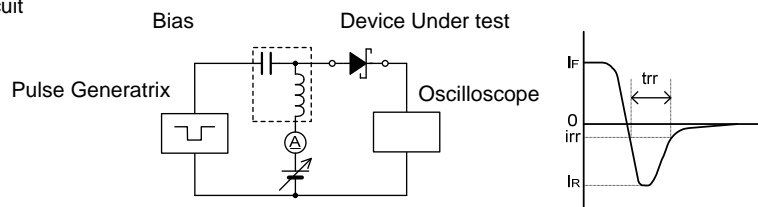
\* The device orientation is fixed in its embossed tape pocket.

## ELECTRICAL CHARACTERISTICS

Ta=25°C

PARAMETER	SYMBOL	TEST CONDITIONS	LIMITS			UNIT
			MIN.	TYP.	MAX.	
Forward Voltage	$V_{F1}$	$I_F=100mA$	-	0.23	0.315	V
	$V_{F2}$	$I_F=500mA$	-	0.30	0.385	V
	$V_{F3}$	$I_F=1A$	-	0.365	0.41	V
Reverse Current	$I_R$	$V_R=40V$	-	0.25	2	mA
Inter-Terminal Capacity	$C_t$	$V_R=1V, f=1MHz$	-	150	-	pF
Reverse Recovery Time <sup>*2</sup>	$t_{rr}$	$I_F=I_R=10mA, irr=1mA$	-	41	-	ns

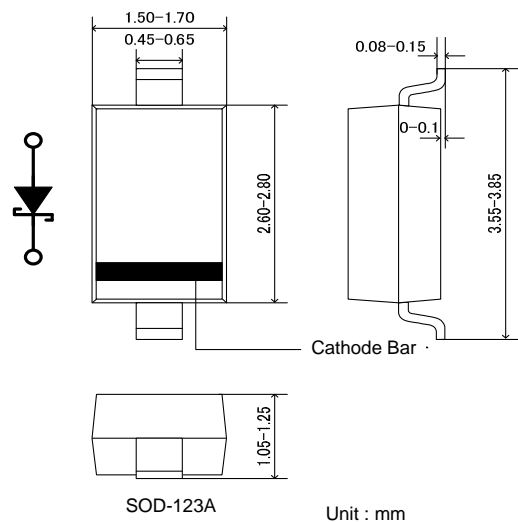
\*2 :  $t_{rr}$  measurement circuit



## APPLICATIONS

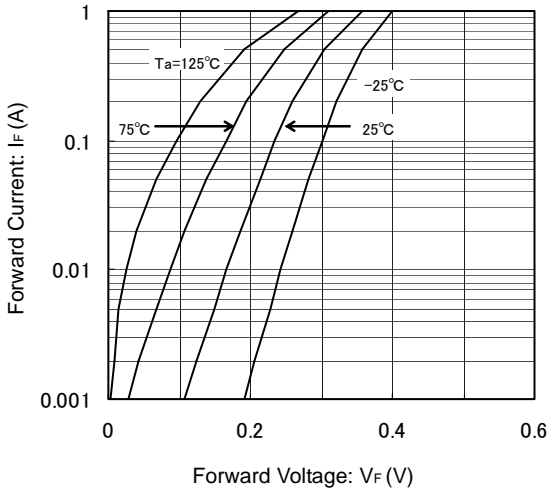
- Rectification
- Protection against reverse connection of battery

## PACKAGING INFORMATION

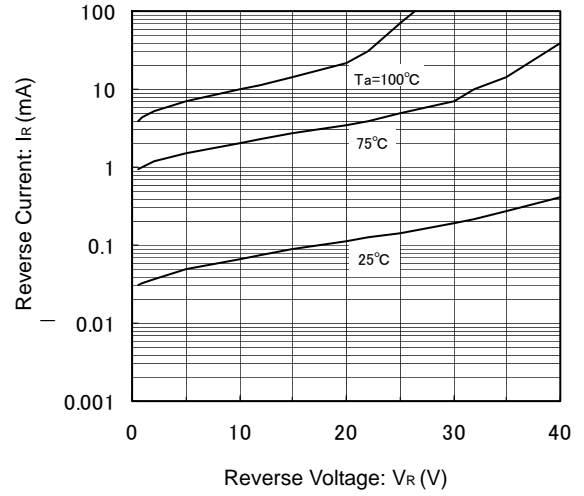


## TYPICAL PERFORMANCE CHARACTERISTICS

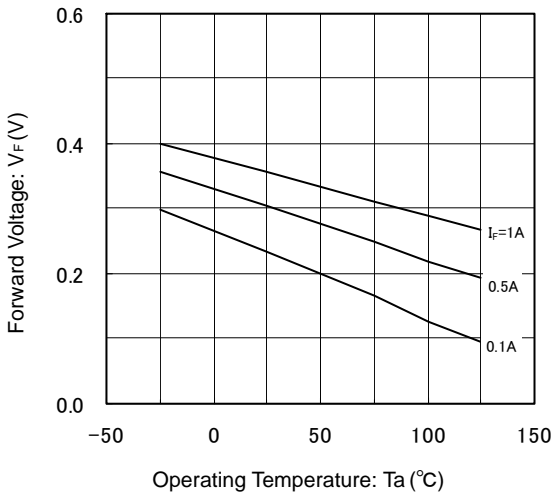
(1) Forward Current vs. Forward Voltage



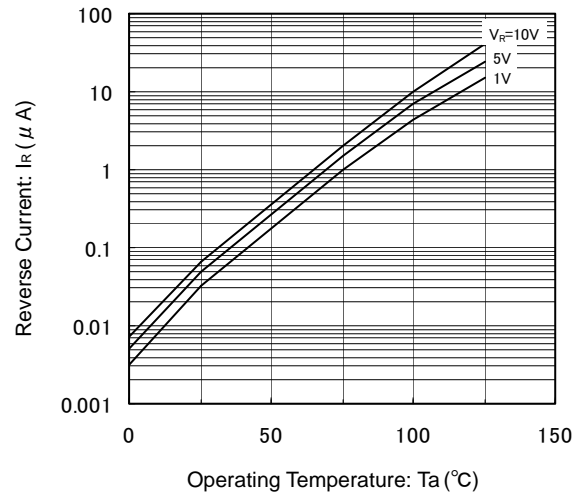
(2) Reverse Current vs. Reverse Voltage



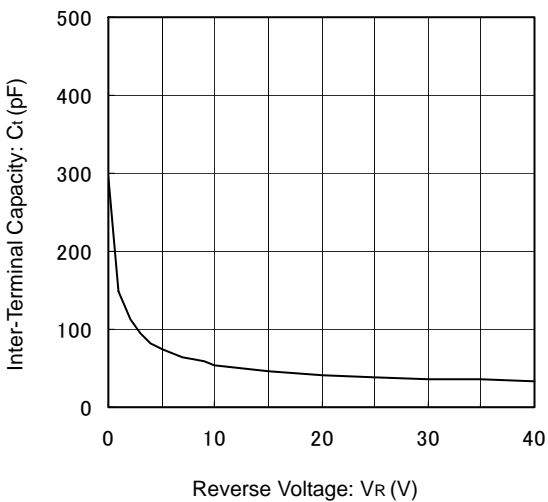
(3) Forward Voltage vs. Operating Temperature



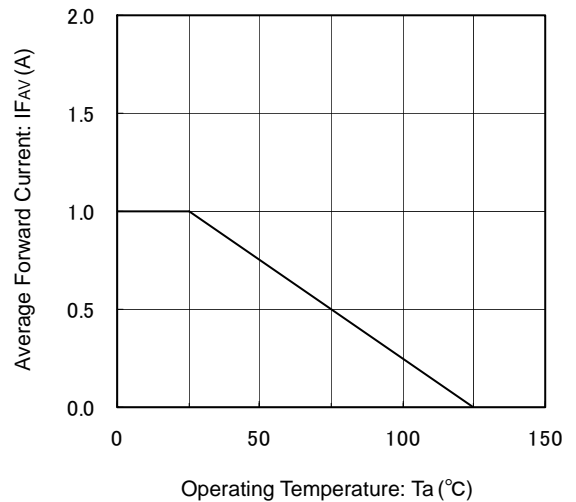
(4) Reverse Current vs. Operating Temperature



(5) Inter-Terminal Capacity vs. Reverse Voltage



(6) Average Forward Current vs. Operating Temperature



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